

May 1993 Revised October 2003

74LVX174

Low Voltage Hex D-Type Flip-Flop with Master Reset

General Description

The LVX174 is a high-speed hex D flip-flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the LOW-to-HIGH clock transition. The device has a Master Reset to simultaneously clear all flip-flops.

Features

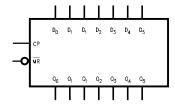
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

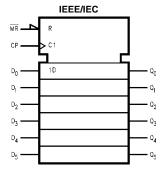
Ordering Code:

Order Number	Package Number	Package Description
74LVX174M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX174SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX174MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

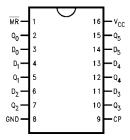
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description				
D ₀ -D ₅	Data Inputs				
CP	Clock Pulse Input				
MR	Master Reset Input				
Q ₀ -Q ₅	Outputs				

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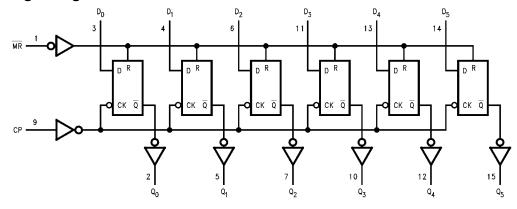
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Truth Table

		Inputs		Outputs
Operating Mode	MR	СР	D _n	Q _n
Reset (Clear)	L	Х	Х	L
Load '1'	Н		Н	Н
Load '0'	Н	_	L	L

- H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Immaterial
 = LOW-to-HIGH Transition

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $\begin{array}{lll} \mbox{V}_{\mbox{\scriptsize I}} = -0.5 \mbox{\scriptsize V} & -20 \mbox{ mA} \\ \mbox{\scriptsize DC Input Voltage (V}_{\mbox{\scriptsize I}}) & -0.5 \mbox{\scriptsize V} \mbox{\scriptsize to 7V} \end{array}$

DC Output Diode Current (I_{OK})

$$\begin{split} \text{V}_{\text{O}} &= -0.5 \text{V} & -20 \text{ mA} \\ \text{V}_{\text{O}} &= \text{V}_{\text{CC}} + 0.5 \text{V} & +20 \text{ mA} \end{split}$$

DC Output Voltage ($V_{\rm O}$) $-0.5 \rm V$ to $V_{\rm CC} + 0.5 \rm V$

DC Output Source

or Sink Current (I_O) $\pm 25 \text{ mA}$

DC V_{CC} or Ground Current

 $(I_{CC} \text{ or } I_{GND})$ ±50 mA

 $\begin{array}{ll} \mbox{Storage Temperature (T_{STG})} & -65^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \\ \mbox{Power Dissipation (P_{D})} & 180\mbox{ mW} \end{array}$

Recommended Operating Conditions (Note 2)

 $\begin{array}{ll} \text{Supply Voltage (V}_{\text{CC}}) & 2.0 \text{V to } 3.6 \text{V} \\ \text{Input Voltage (V}_{\text{I}}) & 0 \text{V to } 5.5 \text{V} \\ \end{array}$

Input Rise and Fall Time ($\Delta t/\Delta V$) 0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	v _{cc}	T _A = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions		
Cymbol		- 66	Min	Тур	Max	Min	Max	Onno	Conditions		
V _{IH}	HIGH Level	2.0	1.5			1.5					
	Input Voltage	3.0	2.0			2.0		V			
		3.6	2.4			2.4					
V _{IL}	LOW Level	2.0			0.5		0.5				
	Input Voltage	3.0			0.8		0.8	V			
		3.6			0.8		0.8				
V _{OH}	HIGH Level	2.0	1.9	2.0		1.9			$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -50 \ \mu\text{A}$ $I_{OH} = -50 \ \mu\text{A}$ $I_{OH} = -4 \ \text{mA}$		
	Output Voltage	3.0	2.9	3.0		2.9		V	$I_{OH} = -50 \mu A$		
		3.0	2.58			2.48			$I_{OH} = -4 \text{ mA}$		
V _{OL}	LOW Level	2.0		0.0	0.1		0.1		$V_{IN} = V_{IL} \text{ or } V_{IH} I_{OL} = 50 \mu\text{A}$		
	Output Voltage	3.0		0.0	0.1		0.1	V	$I_{OL} = 50 \mu A$ $I_{OL} = 4 mA$		
		3.0			0.36		0.44		$I_{OL} = 4 \text{ mA}$		
I _{IN}	Input Leakage Current	3.6			±0.1		±1.0	μΑ	V _{IN} = 5.5V or GND		
I _{CC}	Quiescent Supply Current	3.6			4.0		40.0	μΑ	V _{IN} = V _{CC} or GND		

Noise Characteristics (Note 3)

Symbol	Parameter	V _{CC}	T _A = 25°C		Units	C _I (pF)	
	i arameter	(V)	Тур	Limit	Omits	-[(b.)	
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.3	0.5	V	50	
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	-0.3	-0.5	V	50	
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50	

Note 3: (Input $t_f = t_f = 3 \text{ ns}$)

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AC Electrical Characteristics

Symbol	Parameter	v _{cc}	$T_A = +25^{\circ}C$			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	C _L (pF)
Cyllibol		(V)	Min	Тур	Max	Min	Max	Ullits	OL (p.)
t _{PLH}	Propagation	2.7		7.6	14.5	1.0	17.5		15
t _{PHL}	Delay Time			10.1	18.0	1.0	21.0		50
	CP to Q _n	3.3 ± 0.3		5.9	9.3	1.0	11.0	ns	15
				8.4	12.8	1.0	14.5		50
t _{PHL}	Propagation Delay	2.7		7.9	15.0	1.0	18.5		15
	MR to Q _n			10.4	18.5	1.0	22.0		50
		3.3 ± 0.3		6.2	9.7	1.0	11.5	ns	15
				8.7	13.2	1.0	15.0		50
t _S	Setup Time	2.7	7.5			8.5			
	D _n to CP	3.3 ± 0.3	5.0			6.0			
t _H	Hold Time	2.7	0			0		ns	
	D _n to CP	3.3 ± 0.3	0			0			
t _{REC}	Removal Time	2.7	4.5			4.5			
	MR to CP	3.3 ± 0.3	3.0			3.0		ns	
t _W	Clock Pulse	2.7	6.5			7.5		115	
	Width	3.3 ± 0.3	5.0			5.0			
t _W	MR Pulse	2.7	6.5			7.5			
	Width	3.3 ± 0.3	5.0			5.0		ns	
f _{MAX}	Maximum Clock	2.7	65	130		55			15
	Frequency		45	60		40		MHz	50
		3.3 ± 0.3	115	180		95		IVITZ	15
			65	95		55			50
toslh	Output to Output	2.7			1.5		1.5	20	50
toshl	Skew (Note 4)	3.3			1.5		1.5	ns	

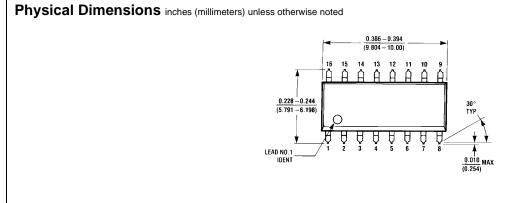
 $\textbf{Note 4:} \ \text{Parameter guaranteed by design.} \ t_{\text{OSLH}} = |t_{\text{PLHm}} - t_{\text{PLHn}}|, \ t_{\text{OSHL}} = |t_{\text{PHLm}} - t_{\text{PHLn}}|$

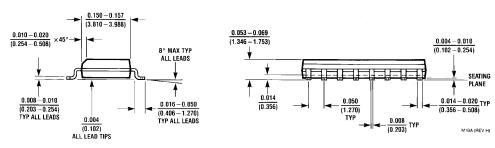
Capacitance

Symbol	Parameter		T _A = +25°C		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
	T didilictor	Min	Тур	Max	Min	Max	Omio
C _{IN}	Input Capacitance		4	10		10	pF
C _{PD}	Power Dissipation Capacitance (Note 5)		29				pF

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

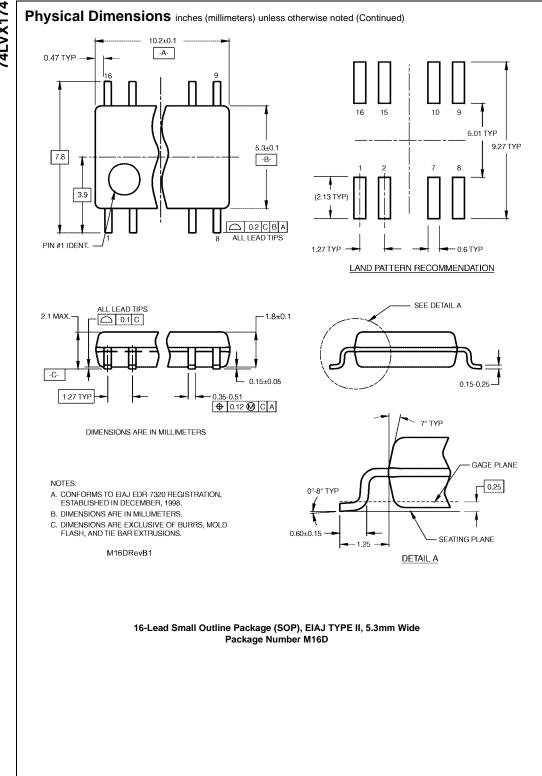
Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{|N|} + |_{CC}}{4 \text{ (per F/F)}}$

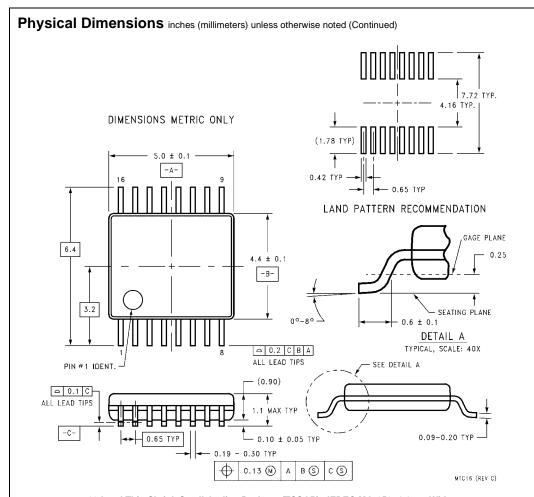




16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A

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16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC16

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